

## BC63916

### **Switching and Amplifier Applications**



## **NPN Epitaxial Silicon Transistor**

### **Absolute Maximum Ratings** T<sub>a</sub>=25°C unless otherwise noted

Symbol	Parameter	Value	Units
V <sub>CER</sub>	Collector-Emitter Voltage at R <sub>BE</sub> =1KΩ	100	V
V <sub>CES</sub>	Collector-Emitter Voltage	100	V
V <sub>CEO</sub>	Collector-Emitter Voltage	80	V
$V_{EBO}$	Emitter-Base Voltage	5	V
I <sub>C</sub>	Collector Current	1	А
P <sub>C</sub>	Collector Power Dissipation	1	W
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Junction Temperature Range	-55 ~ 150	°C

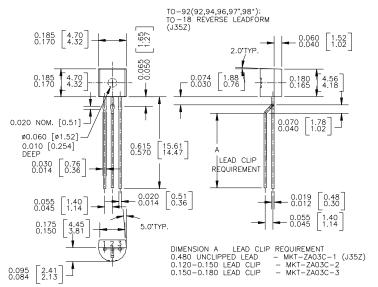
PW=5ms, Duty Cycle=10%

### **Electrical Characteristics** $T_a$ =25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
BV <sub>CBO</sub>	Collector-Base Breakdown Voltage	$I_C = 100 \mu A, I_E = 0$	100			V
BV <sub>CEO</sub>	Collector-Emitter Breakdown Voltage	$I_C = 10 \text{mA}, I_B = 0$	80			V
BV <sub>EBO</sub>	Emitter-Base Breakdown Voltage	$I_E = 10\mu A, I_C = 0$	5.0			V
I <sub>CBO</sub>	Collector Cut-off Current	$V_{CB} = 30V, I_{E} = 0$			100	nA
I <sub>EBO</sub>	Emitter Cut-off Current	$V_{EB} = 5V, I_{C} = 0$			10	μΑ
h <sub>FE1</sub>	DC Current Gain	$V_{CE} = 2V$ , $I_{C} = 5mA$	25			
$h_{FE2}$		$V_{CE} = 2V, I_{C} = 150mA$	100		250	
$h_{FE3}$		$V_{CE} = 2V, I_{C} = 500mA$	25			
V <sub>CE</sub> (sat)	Collector-Emitter Saturation Voltage	$I_C = 500 \text{mA}, I_B = 50 \text{mA}$			0.5	V
V <sub>BE</sub> (on)	Base-Emitter On Voltage	$V_{CE} = 2V, I_{C} = 500 \text{mA}$			1	V
f <sub>T</sub>	Current Gain Bandwidth Product	$V_{CE} = 5V$ , $I_{C}=10$ mA, f = 50MHz		100		MHz

# **Package Dimensions**

## TO-92



Note: All package 97 or 98 transistors are leadformed to this configuration prior to bulk shipment. Order L34Z option if in-line leads are preferred on package 97 or 98.

Dimensions in Millimeters

<sup>\*</sup> Standard Option on 97 & 98 package code

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EnSigna™	$I^2C^{TM}$	$OCX^{TM}$	RapidConfigure™	UHC™
Across the board.	Around the world.™	OCXPro™	RapidConnect™	UltraFET <sup>®</sup>
The Power Franchise™		OPTOLOGIC <sup>®</sup>	SILENT SWITCHER®	VCX <sup>TM</sup>
Programmable Ad	ctive Droop™	OPTOPLANAR™	SMART START™	

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